SEOUL SEMICONDUCTOR

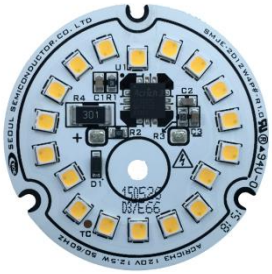
Product Data Sheet

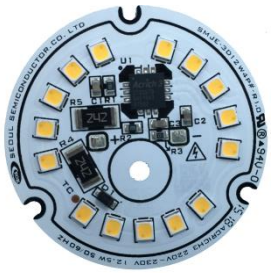
SMJE-XD12W4PX - Acrich3 12W

Integrated AC LED Solution

Acrich3 – 12W

SMJE-XD12W4PX





Product Brief

Description

- The Acrich3 series of products are not need the standard converter essential for conventional general lighting products.
- The converter or driver found in most general lighting products can limit the overall life of the product, but with the Acrich3 series of products the life of the product can more closely be estimated from the LED itself. This will also allow for a much smaller form factor from an overall fixture design allowing for higher creativity in the fixture.
- The modules have a high power factor which can contribute to a higher energy savings in the end application.

Features and Benefits

- Connects directly to AC line voltage Through SPC3.0 (SMJJ-SPCACND)
- High Power Efficiency & Factor
- Low THD
- Long Life Time
- Simple BOM
- Miniaturization
- Lead Free Product
- RoHS Compliant
- TRIAC Dimming

Key Applications

- Bulb Llight

Table 1. Product Selection (CCT)

Part No.	Vin [Vac]	P [W]	Color	CCT [K]	CRI Min.
SMJE-2D12W4PD SMJE-3D12W4PD	120 220	12.5	Cool	4700 – 6000	80
			Neutral	3700 – 4200	
			Warm	2600 – 3200	
SMJE-2D12W4PE SMJE-3D12W4PE	120 220	12.5	Neutral	3700 – 4200	90
			Warm	2600 – 3200	

Table 2. Product Selection (Flux)

Part No.	Vin [Vac]	P [W]	CRI	Flux [lm]		Remark
				Min.	Typ.	
SMJE-2D12W4PD SMJE-3D12W4PD	120 220	12.5	80	910	1,020	12b
				1,020	1,130	12c
SMJE-2D12W4PE SMJE-3D12W4PE	120 220	12.5	90	750	910	12a

Table of Contents

Index	
• Product Brief	1
• Table of Contents	2
• Performance Characteristics	3
• Thermal Resistance	5
• Characteristic Graph	6
• Color Bin Structure	11
• Mechanical Dimensions	17
• Marking Information	19
• Packing Information	20
• Label Information	21
• Handling of Silicone Resin for LEDs	23
• Precaution for Use	24
• Company Information	26

Performance Characteristics

Table 3. Electro Optical Characteristics, T_a = 25ºC

Parameter	Symbol	Value			Unit	Mark
		Min.	Typ.	Max.		
Luminous Flux (@CRI.80)	Φ_V [1]	910	1,020	-	lm	12b
		1,020	1,130	-		12c
Luminous Flux (@CRI.90)		750	910	-		12a
Correlated Color Temperature [3]	CCT [2]	5300	5600	6000	K	B
		4700	5000	5300		C
		3700	4000	4200		E
		2900	3000	3200		G
		2600	2700	2900		H
CRI	Ra	80	-	-	-	PD
		90	-	-	-	PE
Input Voltage	V_{in}		120		Vac	2D
			220			3D
Power Consumption	P	11.2	12.5	13.7	W	12W
Operating Frequency	f		50 / 60		Hz	
Power Factor	PF		Over 0.95		-	@120Vac
			Over 0.88		-	@220Vac
Viewing Angle	$2\Theta_{1/2}$		120		deg.	
Ring Wave Surge [4]	V_s		500		V	
Combination Wave Surge [5]	V_s		2500		V	

Notes :

(1) Φ_V is the total luminous flux output measured with an integrated sphere.
(Measure tolerance = ± 5%)

(2) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

(3) Operating Voltage doesn't indicate the maximum voltage which customers use but means tolerable voltage according to each country's voltage variation rate. It is recommended that the solder pad temperature should be below 85℃.

(4) At 120Vac, seven strikes, 100kHz 2.5kV in accordance with ANSI/IEEE C62.41.2-2002 Category A operation

(5) At 220Vac, Surge withstand in accordance with IEC 61000-4-5

(6) All measurements were made under the standardized environment of Seoul Semiconductor.

Performance Characteristics

Table 4. Absolute Maximum Ratings, T_a = 25ºC

Parameter		Symbol	Unit	Value
Maximum Input Voltage	@120Vac	V_{in}	Vac	144
	@220Vac			264
Power Consumption		P	W	14.5
Operating Temperature		T_s	ºC	< 85℃
Storage Temperature		T_{stg}	ºC	-40 ~ 100
ESD Sensitivity		-	-	±4,000V HBM

Table 5. Intensity rank distribution

Available ranks

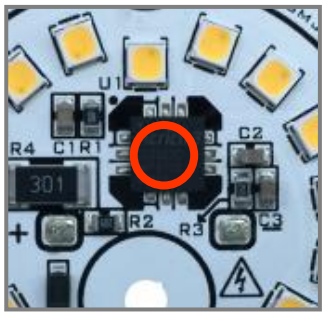
CRI	CCT	CIE	Flux Rank		
80	5300K – 6000K	B	12a	12b	12c
	4700K – 5300K	C	12a	12b	12c
	3700K – 4200K	E	12a	12b	12c
	2900K – 3200K	G	12a	12b	12c
	2600K – 2900K	H	12a	12b	12c
90	3700K – 4200K	E	12a	12b	12c
	2900K – 3200K	G	12a	12b	12c
	2600K – 2900K	H	12a	12b	12c

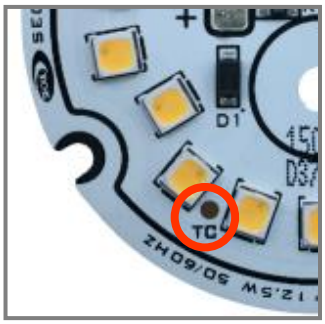
Thermal Resistance

Table 6. Thermal information, Ta = 25ºC

Parameter	Part	Symbol	Unit	Value
Maximum Junction Temperature	LED	T_{J_LED}	℃	125
	Acrich IC	T_{J_IC}	℃	150
Thermal Resistance	LED	$R\theta_{j\text{-}s}$	℃/W	9
	Acrich IC	$R\theta_{j\text{-}case}$	℃/W	11.25

Notes :





The Acrich3 module is recommended to keep under maximum junction temperature. (Table 6)

IC top case temperature (T_{CASE}) and PCB board temperature (T_C) are measured

by thermal coupler at the above point in the figure.

LED lead temperature (T_S) is assumed same with PCB board temperature (T_C).

Maximum temperature calculate as below.

1) Maximum PCB board temperature (= Maximum LED lead temperature)

$T_C = T_{J_LED} - (R\theta_{j\text{-}s} * P_{d_LED})$

$= 125℃ - (9\ ℃/W * 1.5W) = 111.5\ ℃$

2) Maximum Acrich IC top case temperature

$T_{CASE} = T_{J_IC} - (R\theta_{j\text{-}case} * P_{d_IC})$

$= 150℃ - (11.25\ ℃/W * 2.8W) = 118.5℃$

Although this is the maximum temperature, it is recommended to keep the

PCB board temperature under 85℃ and IC top case temperature 110℃

Characteristic Graph

Fig 1. Relative Spectral Distribution vs. Wavelength Characteristic – G, H

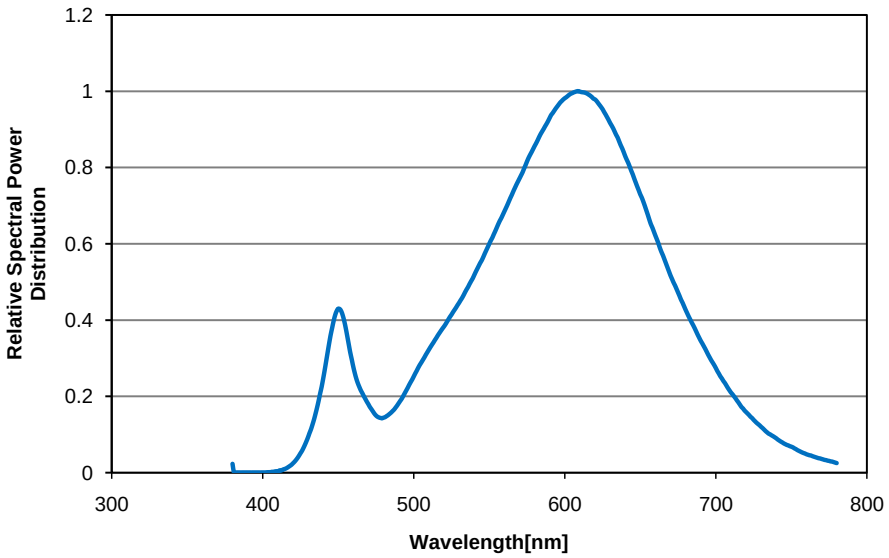
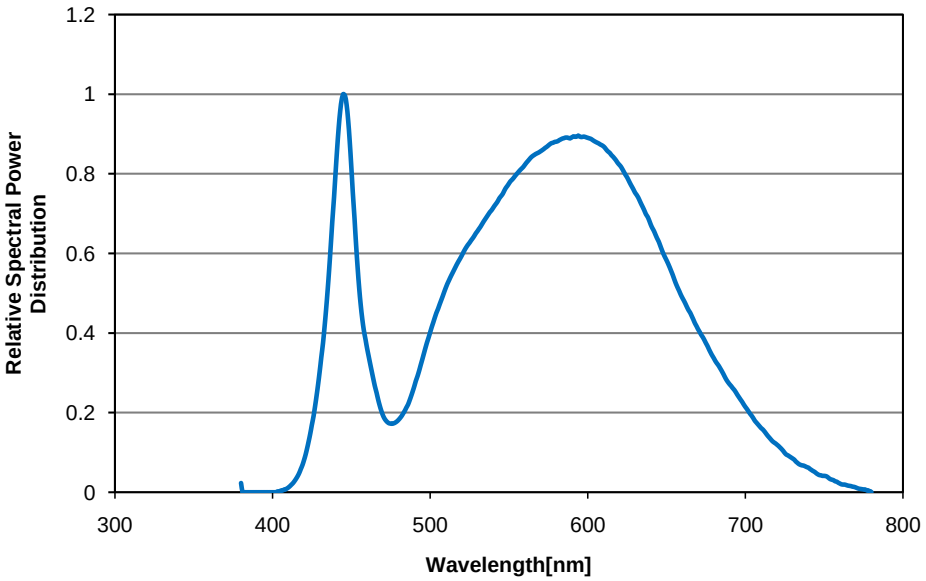
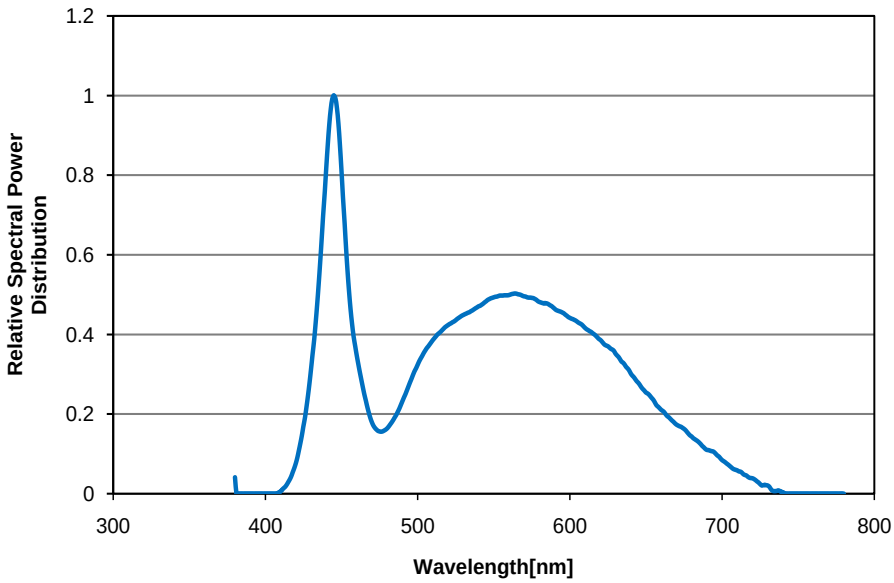


Fig 2. Relative Spectral Distribution vs. Wavelength Characteristic – E



Characteristic Graph

Fig 3. Relative Spectral Distribution vs. Wavelength Characteristic – B, C



Characteristic Graph

Fig 4. Relative Power Distribution vs. Voltage, T_a=25℃, 120V

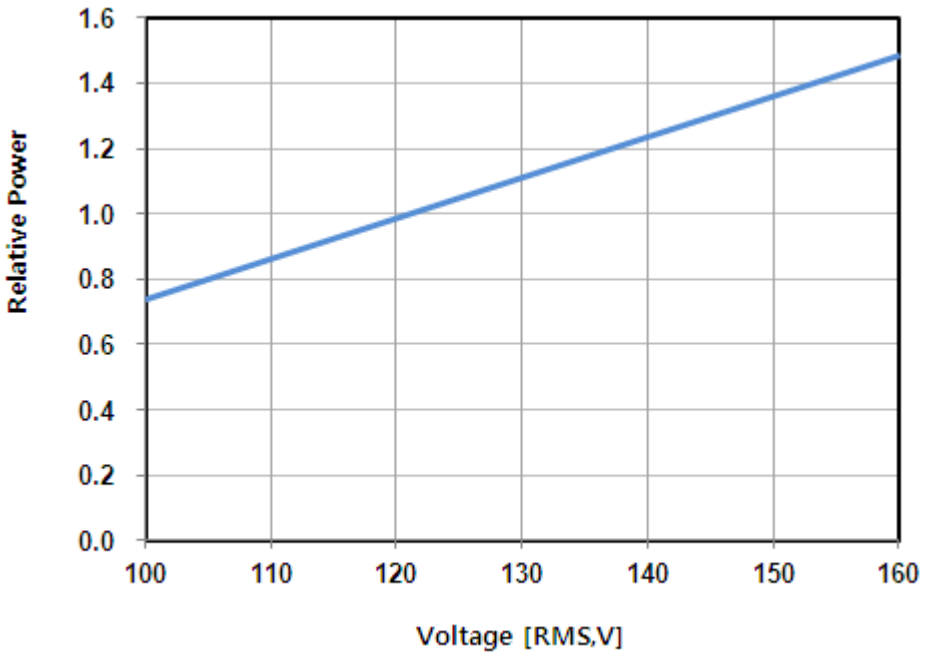
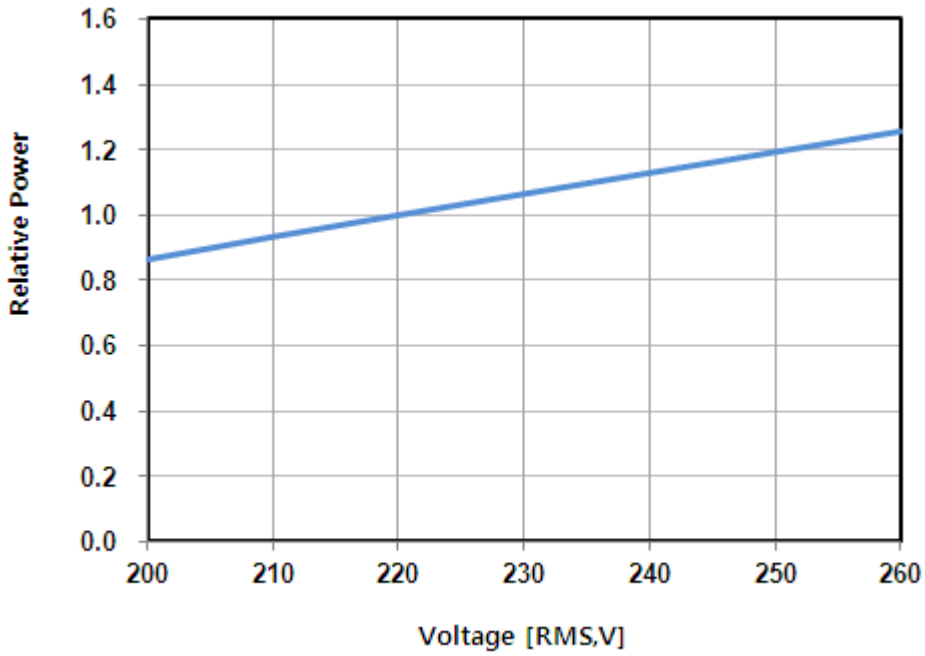


Fig 5. Relative Power Distribution vs. Voltage, T_a=25℃, 220V



Characteristic Graph

Fig 6. Relative Luminous Flux vs. Voltage, T_a=25℃, 120V

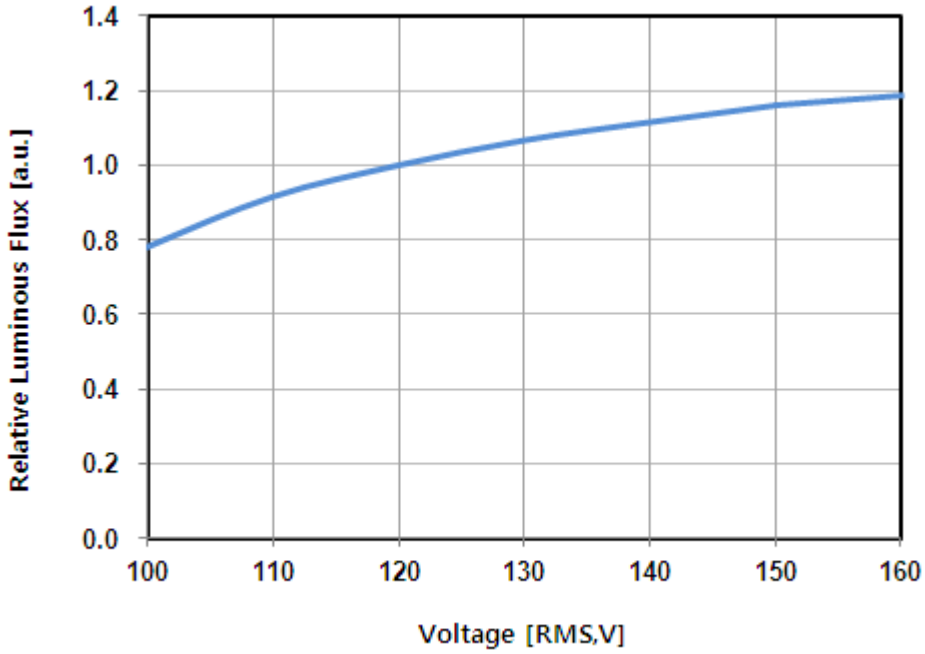
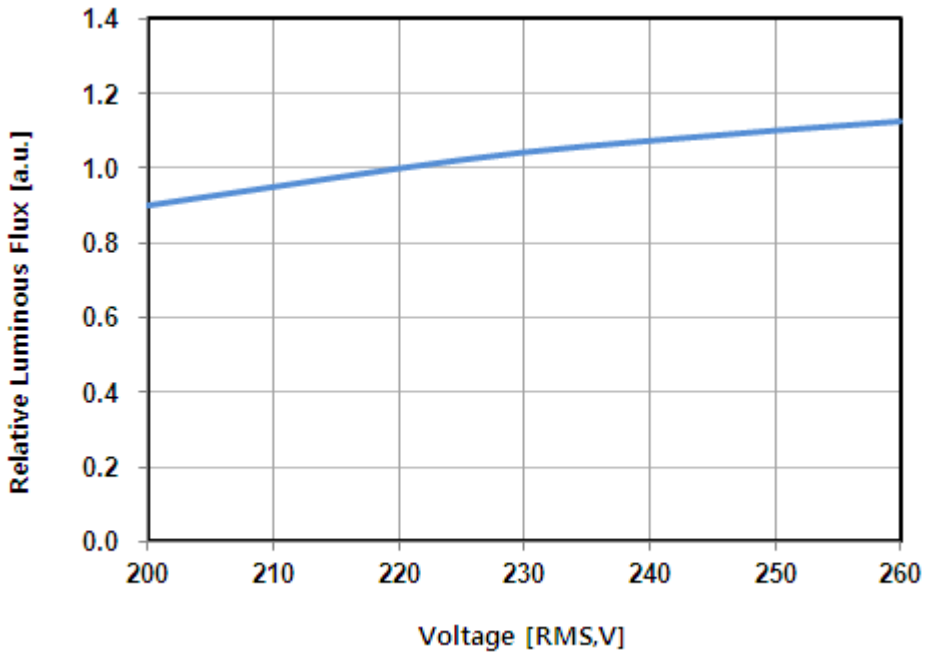
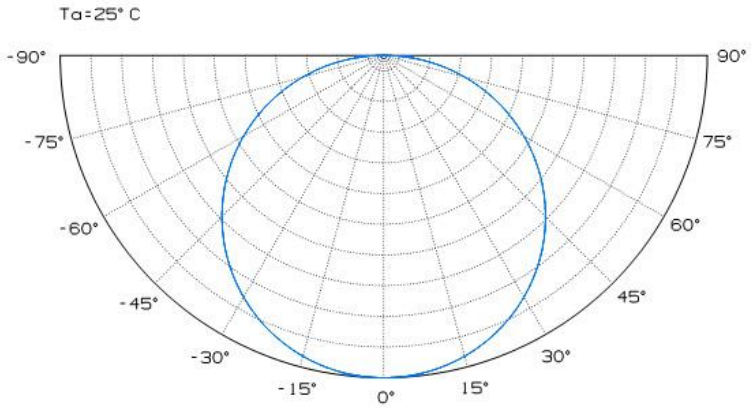


Fig 7. Relative Luminous Flux vs. Voltage, T_a=25℃, 220V



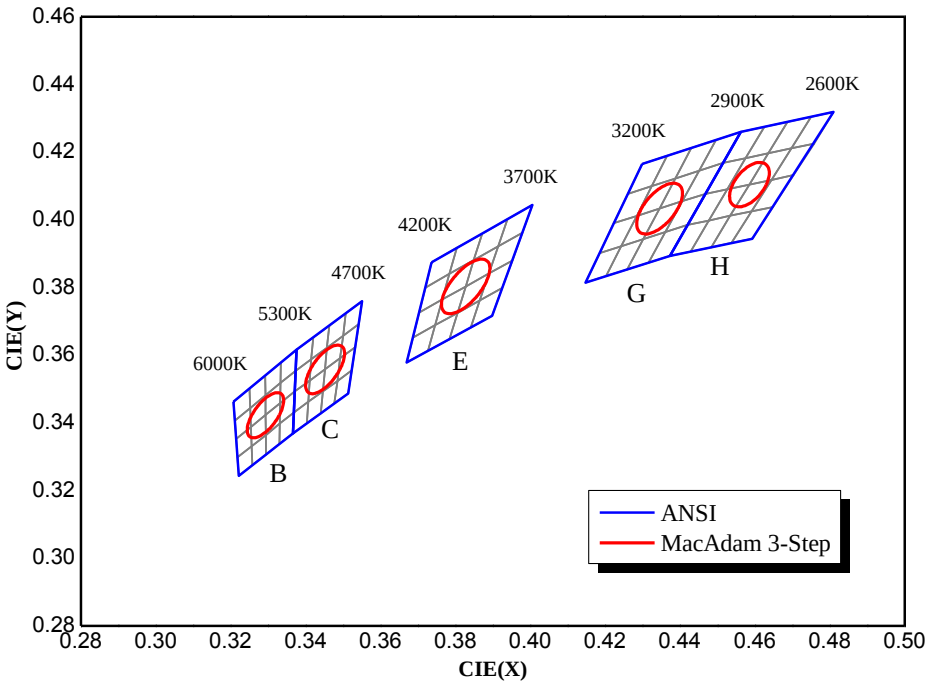
Characteristic Graph

Fig 8. Radiant Pattern, T_a =25℃



Color Bin Structure

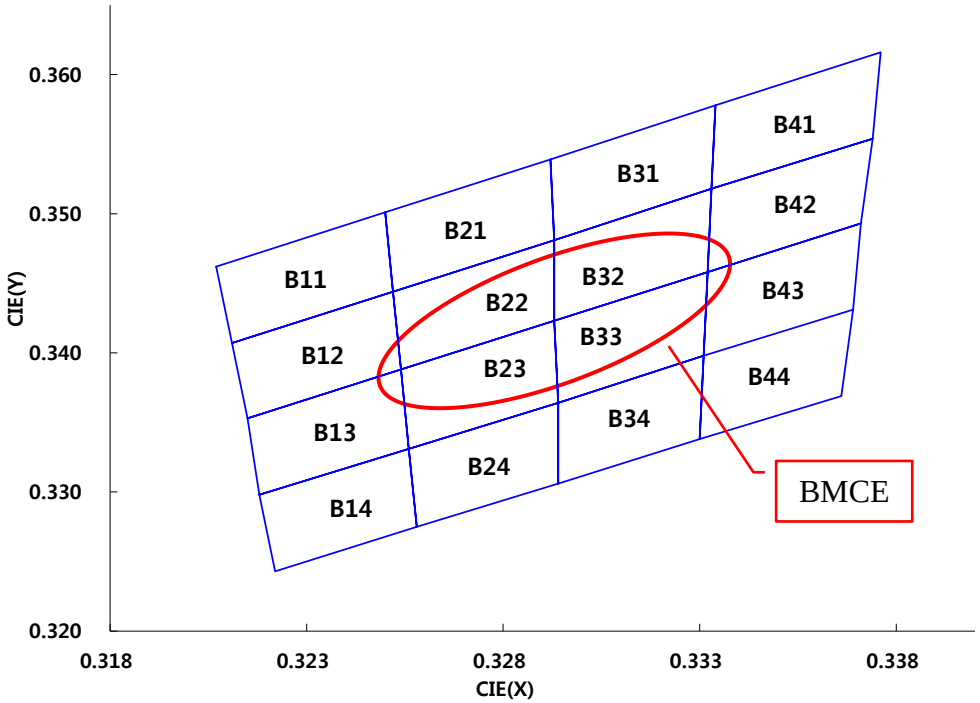
CIE Chromaticity Diagram



Bin	x	y	Bin	x	y	Bin	x	y
B	0.3207	0.3462	C	0.3376	0.3616	E	0.3736	0.3874
	0.3222	0.3243		0.3366	0.3369		0.3670	0.3578
	0.3366	0.3369		0.3515	0.3487		0.3898	0.3716
	0.3376	0.3616		0.3551	0.376		0.4006	0.4044
G	0.4299	0.4165	H	0.4562	0.4260			
	0.4147	0.3814		0.4373	0.3893			
	0.4373	0.3893		0.4593	0.3944			
	0.4562	0.4260		0.4813	0.4319			

Color Bin Structure

CIE Chromaticity Diagram

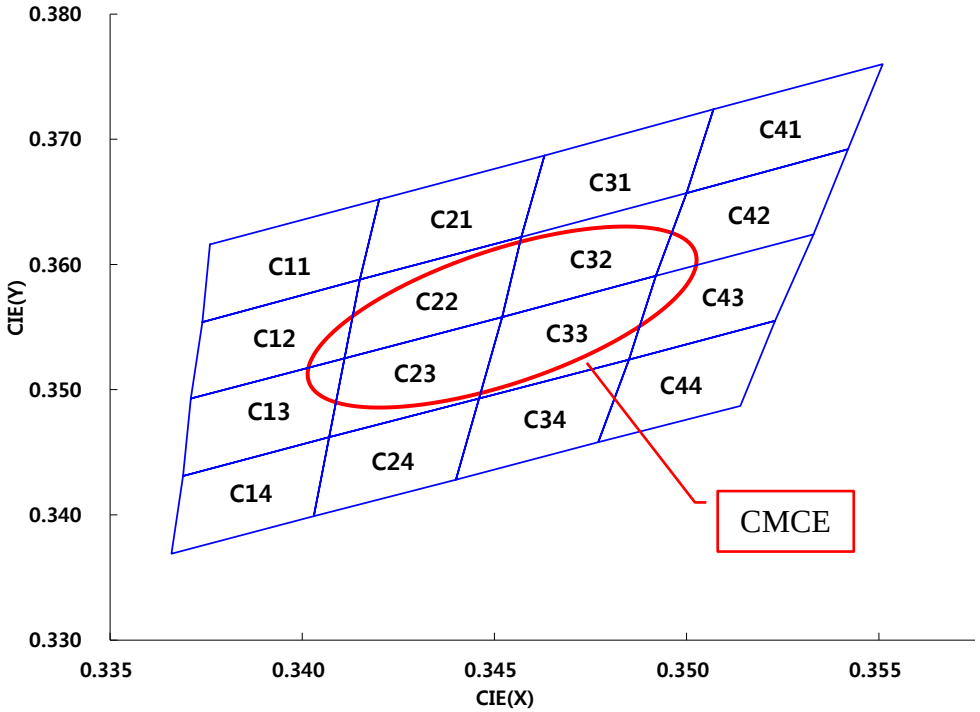


Bin	x	y	Bin	x	y	Bin	x	y	Bin	x	y
B11	0.3207	0.3462	B21	0.3250	0.3501	B31	0.3292	0.3539	B41	0.3334	0.3578
	0.3211	0.3407		0.3252	0.3444		0.3293	0.3481		0.3333	0.3518
	0.3252	0.3444		0.3293	0.3481		0.3333	0.3518		0.3374	0.3554
	0.3250	0.3501		0.3292	0.3539		0.3334	0.3578		0.3376	0.3616
B12	0.3211	0.3407	B22	0.3252	0.3444	B32	0.3293	0.3481	B42	0.3333	0.3518
	0.3215	0.3353		0.3254	0.3388		0.3293	0.3423		0.3332	0.3458
	0.3254	0.3388		0.3293	0.3423		0.3332	0.3458		0.3371	0.3493
	0.3252	0.3444		0.3293	0.3481		0.3333	0.3518		0.3374	0.3554
B13	0.3215	0.3353	B23	0.3254	0.3388	B33	0.3293	0.3423	B43	0.3332	0.3458
	0.3218	0.3298		0.3256	0.3331		0.3294	0.3364		0.3331	0.3398
	0.3256	0.3331		0.3294	0.3364		0.3331	0.3398		0.3369	0.3431
	0.3254	0.3388		0.3293	0.3423		0.3332	0.3458		0.3371	0.3493
B14	0.3218	0.3298	B24	0.3256	0.3331	B34	0.3294	0.3364	B44	0.3331	0.3398
	0.3222	0.3243		0.3258	0.3275		0.3294	0.3306		0.3330	0.3338
	0.3258	0.3275		0.3294	0.3306		0.3330	0.3338		0.3366	0.3369
	0.3256	0.3331		0.3294	0.3364		0.3331	0.3398		0.3369	0.3431

BMCE	
Center Point	0.3293 , 0.3423
Major Axis a	0.0071
Major Axis b	0.0030
Ellipse Rotation Angle	59

Color Bin Structure

CIE Chromaticity Diagram

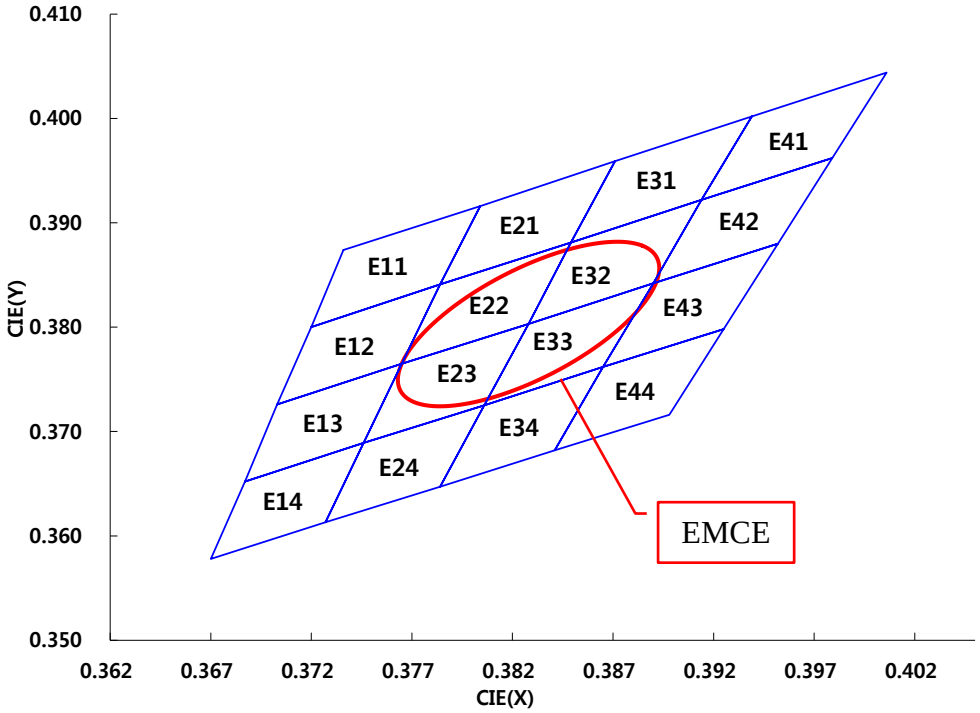


Bin	x	y	Bin	x	y	Bin	x	y	Bin	x	y
C11	0.3376	0.3616	C21	0.3420	0.3652	C31	0.3463	0.3687	C41	0.3507	0.3724
	0.3374	0.3554		0.3415	0.3588		0.3457	0.3622		0.3500	0.3657
	0.3415	0.3588		0.3457	0.3622		0.3500	0.3657		0.3542	0.3692
	0.3420	0.3652		0.3463	0.3687		0.3507	0.3724		0.3551	0.3760
C12	0.3374	0.3554	C22	0.3415	0.3588	C32	0.3457	0.3622	C42	0.3500	0.3657
	0.3371	0.3493		0.3411	0.3525		0.3452	0.3558		0.3492	0.3591
	0.3411	0.3525		0.3452	0.3558		0.3492	0.3591		0.3533	0.3624
	0.3415	0.3588		0.3457	0.3622		0.3500	0.3657		0.3542	0.3692
C13	0.3371	0.3493	C23	0.3411	0.3525	C33	0.3452	0.3558	C43	0.3492	0.3591
	0.3369	0.3431		0.3407	0.3462		0.3446	0.3493		0.3485	0.3524
	0.3407	0.3462		0.3446	0.3493		0.3485	0.3524		0.3523	0.3555
	0.3411	0.3525		0.3452	0.3558		0.3492	0.3591		0.3533	0.3624
C14	0.3369	0.3431	C24	0.3407	0.3462	C34	0.3446	0.3493	C44	0.3485	0.3524
	0.3366	0.3369		0.3403	0.3399		0.3440	0.3428		0.3477	0.3458
	0.3403	0.3399		0.3440	0.3428		0.3477	0.3458		0.3514	0.3487
	0.3407	0.3462		0.3446	0.3493		0.3485	0.3524		0.3523	0.3555

CMCE	
Center Point	0.3452 , 0.3558
Major Axis a	0.0081
Major Axis b	0.0035
Ellipse Rotation Angle	60

Color Bin Structure

CIE Chromaticity Diagram

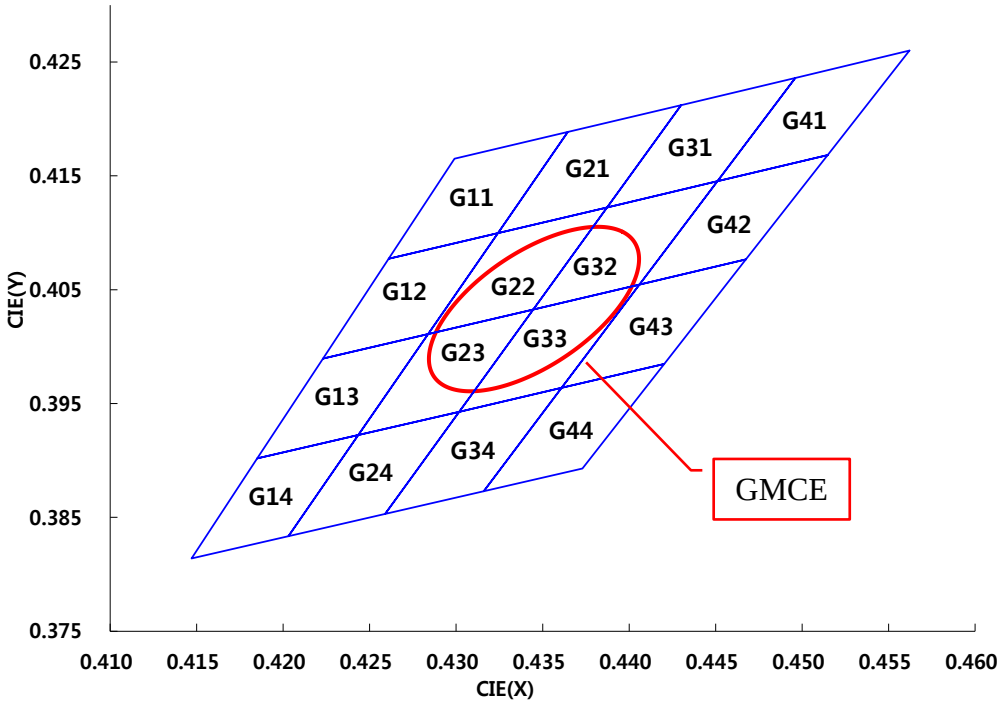


Bin	x	y	Bin	x	y	Bin	x	y	Bin	x	y
E11	0.3736	0.3874	E21	0.3804	0.3916.6	E31	0.3871	0.3959	E41	0.3939	0.4002
	0.3720	0.3800		0.3784	0.3841		0.3849	0.3881		0.3914	0.3922
	0.3784	0.3841		0.3849	0.3881		0.3914	0.3922		0.3979	0.3962
	0.3804	0.3916		0.3871	0.3959		0.3939	0.4002		0.4006	0.4044
E12	0.3720	0.3800	E22	0.3784	0.3841	E32	0.3849	0.3881	E42	0.3914	0.3922
	0.3703	0.3726		0.3765	0.3765		0.3828	0.3803		0.3890	0.3842
	0.3765	0.3765		0.3828	0.3803		0.3890	0.3842		0.3952	0.3880
	0.3784	0.3841		0.3849	0.3881		0.3914	0.3922		0.3979	0.3962
E13	0.3703	0.3726	E23	0.3765	0.3765	E33	0.3828	0.3803	E43	0.3890	0.3842
	0.3687	0.3652		0.3746	0.3689		0.3806	0.3725		0.3865	0.3762
	0.3746	0.3689		0.3806	0.3725		0.3865	0.3762		0.3925	0.3798
	0.3765	0.3765		0.3828	0.3803		0.3890	0.3842		0.3952	0.3880
E14	0.3687	0.3652	E24	0.3746	0.3689	E34	0.3806	0.3725	E44	0.3865	0.3762
	0.3670	0.3578		0.3727	0.3613		0.3784	0.3647		0.3841	0.3682
	0.3727	0.3613		0.3784	0.3647		0.3841	0.3682		0.3898	0.3716
	0.3746	0.3689		0.3806	0.3725		0.3865	0.3762		0.3925	0.3798

EMCE	
Center Point	0.3828 , 0.3803
Major Axis a	0.0094
Major Axis b	0.0040
Ellipse Rotation Angle	53

Color Bin Structure

CIE Chromaticity Diagram

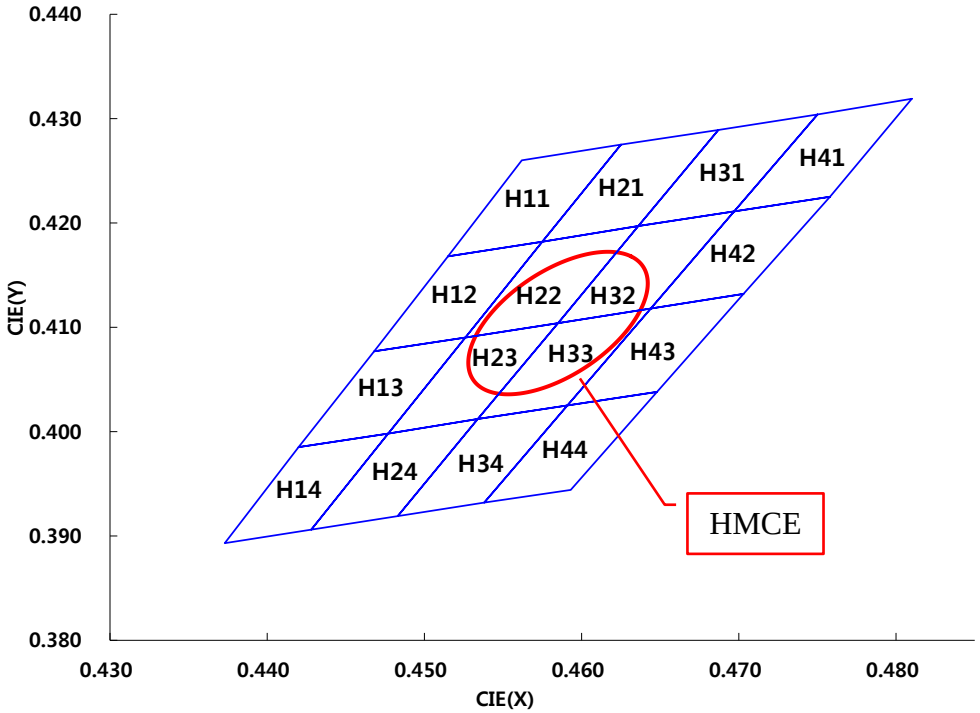


Bin	x	y	Bin	x	y	Bin	x	y	Bin	x	y
G11	0.4299	0.4165	G21	0.4364	0.4188	G31	0.4430	0.4212	G41	0.4496	0.4236
	0.4261	0.4077		0.4324	0.4099		0.4387	0.4122		0.4451	0.4145
	0.4324	0.4100		0.4387	0.4122		0.4451	0.4145		0.4514	0.4168
	0.4365	0.4189		0.4430	0.4212		0.4496	0.4236		0.4562	0.4260
G12	0.4261	0.4077	G22	0.4324	0.4100	G32	0.4387	0.4122	G42	0.4451	0.4145
	0.4223	0.3990		0.4284	0.4011		0.4345	0.4033		0.4406	0.4055
	0.4284	0.4011		0.4345	0.4033		0.4406	0.4055		0.4468	0.4077
	0.4324	0.4100		0.4387	0.4122		0.4451	0.4145		0.4515	0.4168
G13	0.4223	0.3990	G23	0.4284	0.4011	G33	0.4345	0.4033	G43	0.4406	0.4055
	0.4185	0.3902		0.4243	0.3922		0.4302	0.3943		0.4361	0.3964
	0.4243	0.3922		0.4302	0.3943		0.4361	0.3964		0.4420	0.3985
	0.4284	0.4011		0.4345	0.4033		0.4406	0.4055		0.4468	0.4077
G14	0.4243	0.3922	G24	0.4302	0.3943	G34	0.4302	0.3943	G44	0.4361	0.3964
	0.4203	0.3834		0.4259	0.3853		0.4259	0.3853		0.4316	0.3873
	0.4147	0.3814		0.4203	0.3834		0.4316	0.3873		0.4373	0.3893
	0.4185	0.3902		0.4243	0.3922		0.4361	0.3964		0.4420	0.3985

GMCE	
Center Point	0.4345 , 0.4033
Major Axis a	0.0085
Major Axis b	0.0041
Ellipse Rotation Angle	53

Color Bin Structure

CIE Chromaticity Diagram

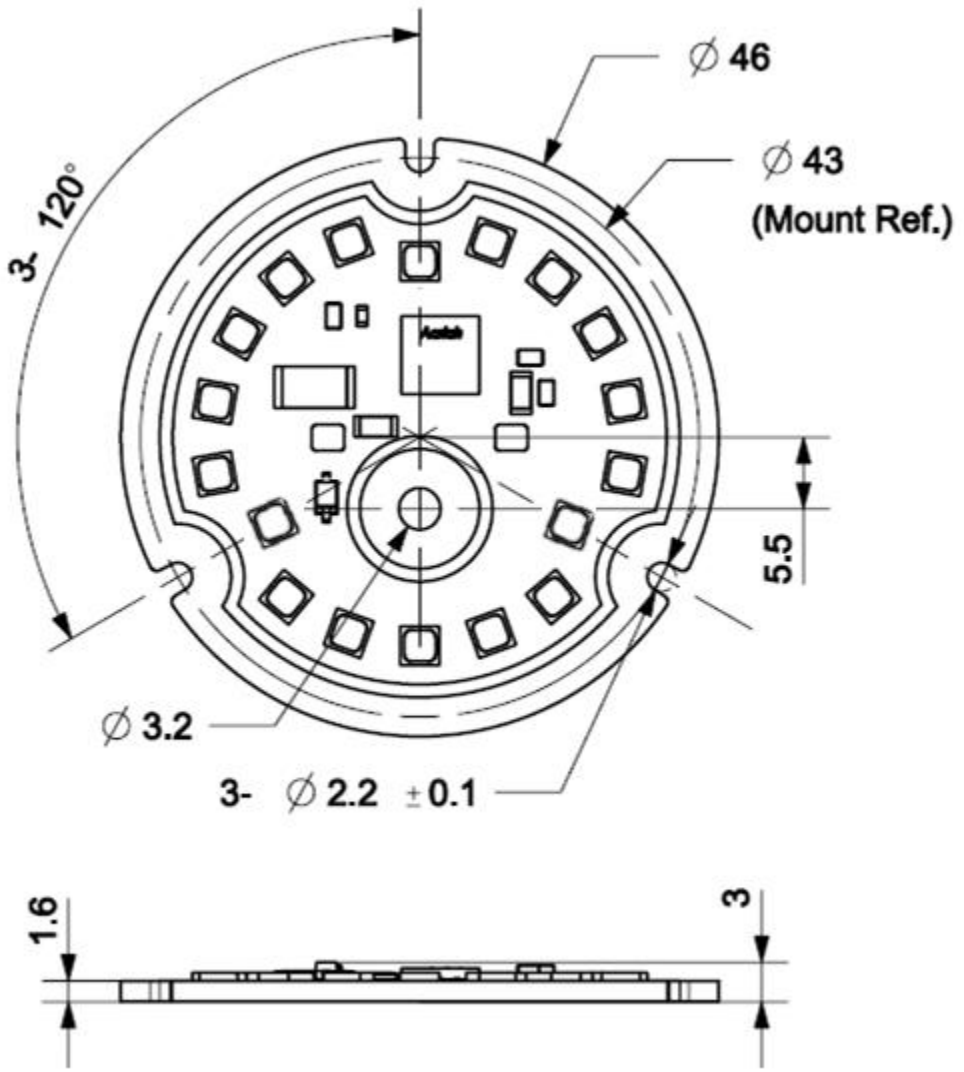


Bin	x	y	Bin	x	y	Bin	x	y	Bin	x	y
H11	0.4562	0.4260	H21	0.4625	0.4275	H31	0.4687	0.4289	H41	0.4750	0.4304
	0.4515	0.4168		0.4575	0.4182		0.4636	0.4197		0.4697	0.4211
	0.4575	0.4182		0.4636	0.4197		0.4697	0.4211		0.4758	0.4225
	0.4625	0.4275		0.4687	0.4289		0.4750	0.4304		0.4810	0.4319
H12	0.4515	0.4168	H22	0.4575	0.4182	H32	0.4636	0.4197	H42	0.4697	0.4211
	0.4468	0.4077		0.4526	0.4090		0.4585	0.4104		0.4644	0.4118
	0.4526	0.4090		0.4585	0.4104		0.4644	0.4118		0.4703	0.4132
	0.4575	0.4182		0.4636	0.4197		0.4697	0.4211		0.4758	0.4225
H13	0.4468	0.4077	H23	0.4526	0.4090	H33	0.4585	0.4104	H43	0.4644	0.4118
	0.4420	0.3985		0.4477	0.3998		0.4534	0.4012		0.4591	0.4025
	0.4477	0.3998		0.4534	0.4012		0.4591	0.4025		0.4648	0.4038
	0.4526	0.4090		0.4585	0.4104		0.4644	0.4118		0.4703	0.4132
H14	0.4420	0.3985	H24	0.4477	0.3998	H34	0.4534	0.4012	H44	0.4591	0.4025
	0.4373	0.3893		0.4428	0.3906		0.4483	0.3919		0.4538	0.3932
	0.4428	0.3906		0.4483	0.3919		0.4538	0.3932		0.4593	0.3944
	0.4477	0.3998		0.4534	0.4012		0.4591	0.4025		0.4648	0.4038

HMCE	
Center Point	0.4585 , 0.4104
Major Axis a	0.0079
Major Axis b	0.0041
Ellipse Rotation Angle	54

Mechanical Dimensions

SMJE-2D12W4PX (120V)

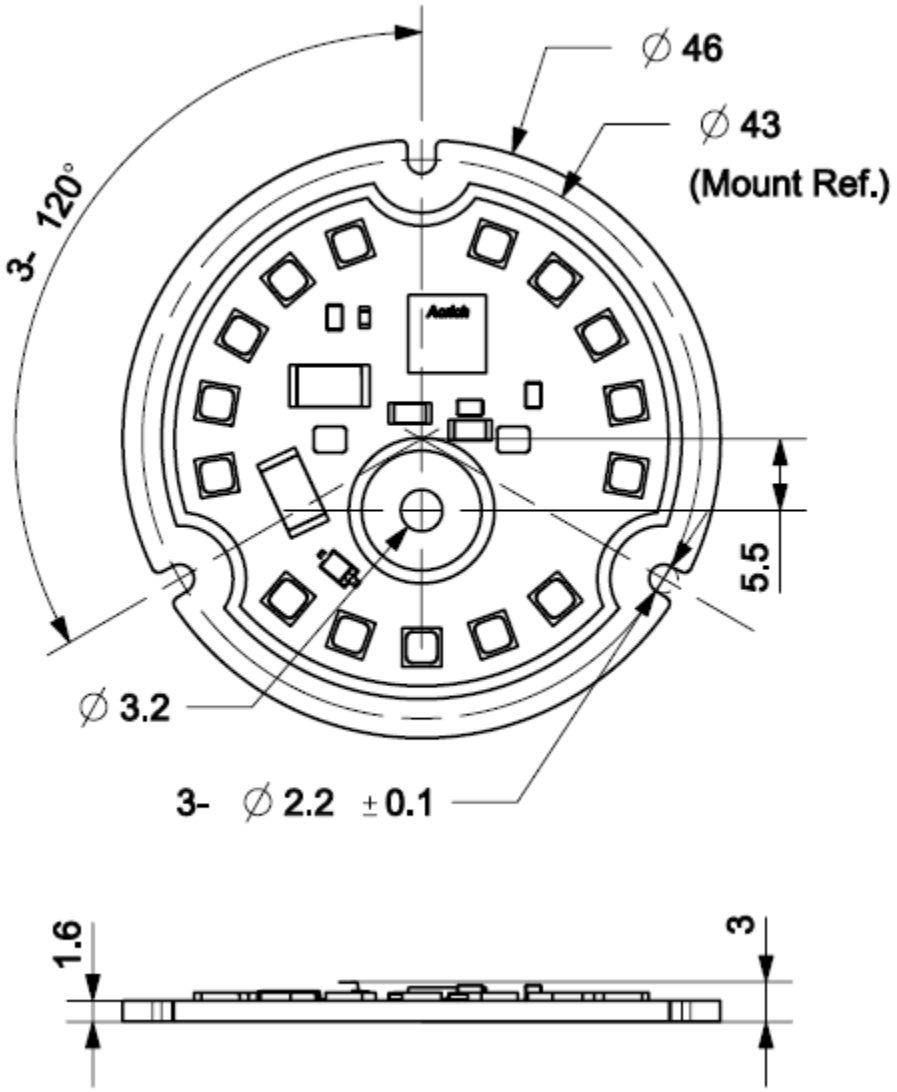


Notes :

(1) All dimensions are in millimeters. (Tolerance : ±0.2)
(2) Scale : None

Mechanical Dimensions

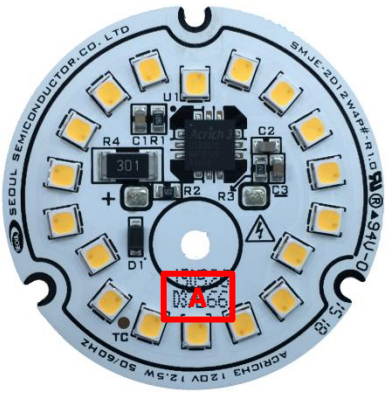
SMJE-3D12W4PX (220V)



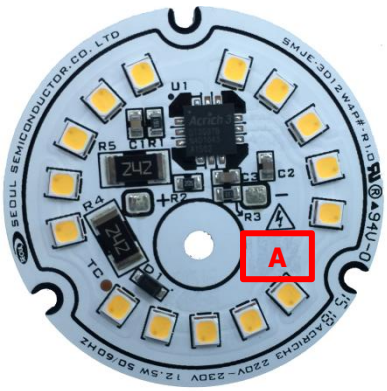
Notes :

(1) All dimensions are in millimeters. (Tolerance : ±0.2)
(2) Scale : None

Marking Information



<SMJE-2D12W4P#>



<SMJE-3D12W4P#>

A : **ex) 180117F Db33G11**

- Description

1 8 0 1 1 7 F
① ②
D b 3 3 G 1 1
③ ④ ⑤⑥⑦

① SMT Date (YYMMDD, 6 Digits)
② SMT Site (1 Digit)
③ CRI Min. (1 Digit)
④ Module Flux Bin (3 Digits)
⑤ CCT (1 Digit)
⑥ CCT Combination NO. (1 Digit)
⑦ VF Combination NO. (1 Digit)

③		④				⑥			⑦		
Marking	CRI	Type	Marking	Bin A	Bin B	Marking	Bin A	Bin B	Marking	Bin A	Bin B
D	80	a	88	K28	K28	*0	*22	*33	1	D1	D1
E	90		99	K29	K29	*1	*23	*32		I1	I1
		b	11	L31	L31	*2	*33	*22	2	D1	D2
			33	L33	L33	*3	*32	*23		I1	I2
			55	L35	L35	*4	*MC	*MC	3	D2	D1
		c	77	L37	L37	*5	*22	*22		I2	I1
			99	L39	L39	*6	*23	*23	4	D1	D3
						*7	*32	*32		I1	I3
						*8	*33	*33	5	D3	D1
						*9	*22	*34		I3	I1
						*A	*22	*43	6	D2	D2
						*B	*22	*44		I2	I2
						*C	*23	*31	7	D2	D3
						*D	*23	*41		I2	I3
						*E	*23	*42	8	D3	D2
						*F	*32	*13		I3	I2
						*G	*32	*14	9	D3	D3
						*H	*32	*24		I3	I3
						*I	*33	*11			
						*J	*33	*12			
						*K	*33	*21			
						*M	MCE	MCE			

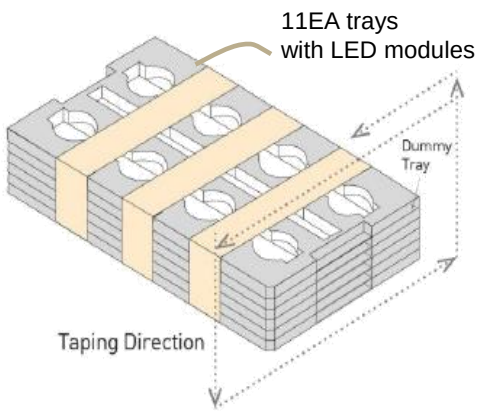
* CCT Mark from *0 to *4 and *M are MacAdam 3-step

Packing

1. Tray information

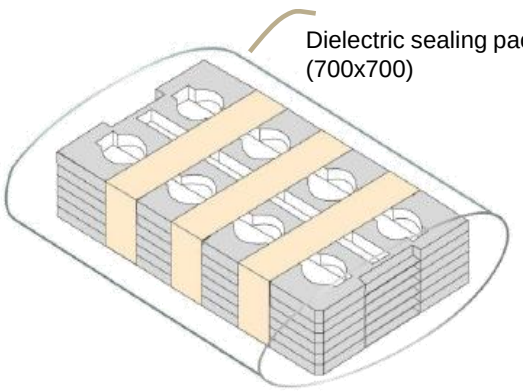
- 72 PCS LED modules packed per tray

2. Tray stack and taping

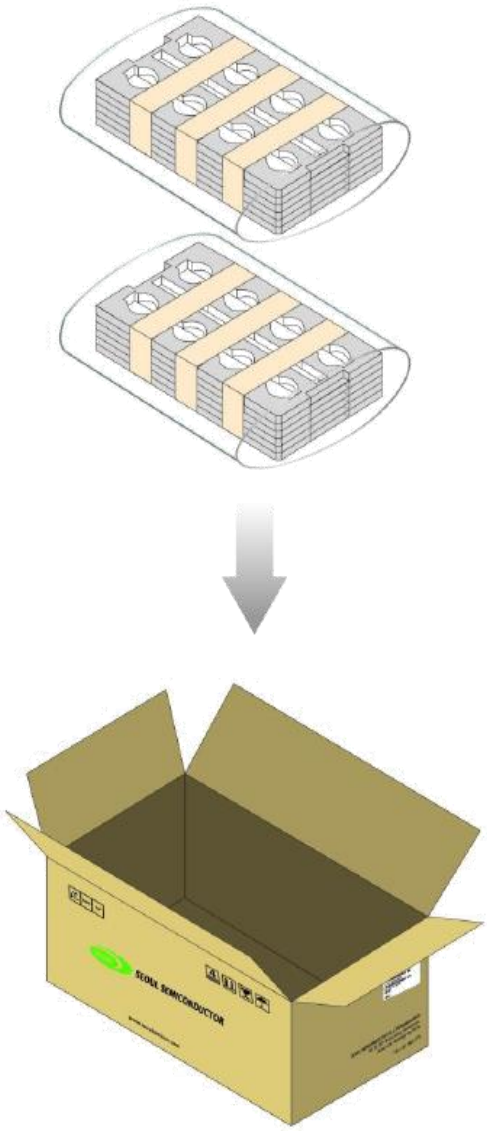


- 10 LED module trays and additional 1 dummy trays each up of box
- Add silica gel (1EA) on top of the tray

3. Sealing packing



4. Box information & packing



- 720 PCS modules per BOX 1EA
- 1 Box : 72 PCS per tray x 10 trays = 720 PCS

Label Information

Model No.	**SMJE-2D12W4PX** (1)
Marking	**Db33G11** (2)
Rank	c UL us **12b-G-80-3step** (3)
Quantity	**XXX**
Date	**YYMDDXXXXX-XXXXXXX**
SEOUL	**SEOUL SEMICONDUCTOR CO.,LTD.**

Notes

(1) The model number designation is explained as follow
- SMJE : Seoul Semiconductor internal code
- 2D : Input Voltage (2D = 120V)
- 12W : About Power Consumption
- 4 : Acrich IC Version 3.0
- PX : MJT PKG (PD : SAW8C72A, PE : SAW9C72A)

(2) It represents the module marking information.

(3) It represents module specification
- Flux Rank (12a / 12b / 12c), CCT Rank (B / C / E / G / H), Minimum of CRI (80 or 90)
- Combination Type : All bin (ALL) or MacAdam 3-Step (3-Step)

(4) It is attached to the top of a sealing pack & the bottom right corner of the box.

TOTAL Quantity

XXX

SEOUL **SEOUL SEMICONDUCTOR CO.,LTD.**

Notes

(1) It is attached to the bottom right corner of the box.

Label Information

Model No.	**SMJE-3D12W4PX** (1)
Marking	**Db33G11** (2)
Rank	**12b-G-80-3step** (3)
Quantity	**XXX**
Date	**YYMDDXXXXX-XXXXXXX**
SEOUL	**SEOUL SEMICONDUCTOR CO.,LTD.**

Notes

(1) The model number designation is explained as follow
- SMJE : Seoul Semiconductor internal code
- 3D : Input Voltage (3D = 220V)
- 12W : About Power Consumption
- 4 : Acrich IC Version 3.0
- PX : MJT PKG (PD : SAW8CF2A, PE : SAW9CF2A)

(2) It represents the module marking information.

(3) It represents module specification
- Flux Rank (12a / 12b / 12c), CCT Rank (B / C / E / G / H), Minimum of CRI (80 or 90)
- Combination Type : All bin (ALL) or MacAdam 3-Step (3-Step)

(4) It is attached to the top of a sealing pack & the bottom right corner of the box.

TOTAL Quantity

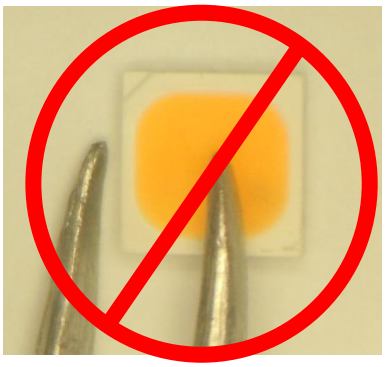
XXX

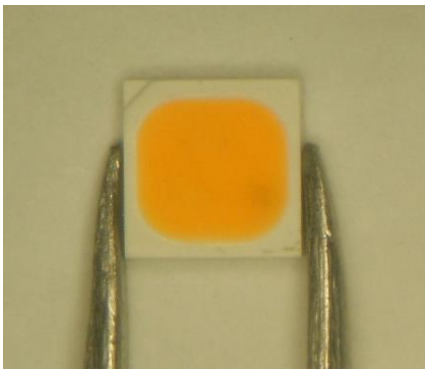
SEOUL **SEOUL SEMICONDUCTOR CO.,LTD.**

Notes

(1) It is attached to the bottom right corner of the box.

Handling of Silicone Resin for LEDs





(1) Acrich3 series is encapsulated with silicone resin for high optical efficiency.

(2) Please do not touch the silicone resin area with sharp objects such as pincette(tweezers).

(3) Finger prints on silicone resin area may affect the performance.

(4) Please store LEDs in covered containers to prevent dust accumulation as this may affect performance.

(5) Excessive force more than 3000gf to the silicone lens can result in fatal or permanent damage with LEDs.

(6) Please do not cover the silicone resin area with any other resins such as epoxy, urethane, etc.

Precaution for Use

(1) Please review the Acrich3 Application Note for proper protective circuitry usage.

(2) Please note, Acrich3 products run off of high voltage, therefore caution should be taken when working near Acrich3 products.

(3) Make sure proper discharge prior to starting work.

(4) DO NOT touch any of the circuit board, components or terminals with body or metal while circuit is active.

(5) Please do not add or change wires while Acrich3 circuit is active.

(6) Long time exposure to sunlight or UV can cause the lens to discolor.

(7) Please do not use adhesives to attach the LED that outgas organic vapor.

(8) Please do not use together with the materials containing Sulfur.

(9) Please do not assemble in conditions of high moisture and/or oxidizing gas such as Cl, H_2S, NH_3, SO_2, NO_x, etc.

(10) Please do not make any modification on module.

(11) Please be cautious when soldering to board so as not to create a short between different trace patterns.

(12) Do not impact or place pressure on this product because even a small amount of pressure can damage the product. The product should also not be placed in high temperatures, high humidity or direct sunlight since the device is sensitive to these conditions.

(13) When storing devices for a long period of time before usage, please following these guidelines:
* The devices should be stored in the anti-static bag that it was shipped in from Seoul-Semiconductor with opening.
* If the anti-static bag has been opened, re-seal preventing air and moisture from being present in the bag.

(14) LEDs and IC are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). The acrich3 product should also not be installed in end equipment without ESD protection. Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

Precaution for Use

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event.
One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:
- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:
- Humidity control (ESD gets worse in a dry environment)

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device.
The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
  (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires
- This damage usually appears due to the thermal stress produced during the EOS event

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device

Company Information

Published by

Seoul Semiconductor © 2013 All Rights Reserved.

Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

Legal Disclaimer

Information in this document is provided in connection with Seoul Semiconductor products. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Seoul Semiconductor hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party. The appearance and specifications of the product can be changed to improve the quality and/or performance without notice.

Revision History

Revision	Date	Page	Remarks
0.0	01-06-2015	All	The first edition.
1.0	2015-06-02	All	Initial datasheet released
2.0	2015-10-02	19, 21	Change PCB Marking and Label Contents
3.0	2017-01-17	All	Add UL mark, Add MCE bin and L39 rank Add table of Intensity rank distribution